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New Associate Editor *U. Moon* 1955

REGULAR PAPERS

- Transmitter Linearization by Beamforming *C. Liang and B. Razavi* 1956
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- A 122-GHz SiGe-Based Signal-Generation Chip Employing a Fundamental-Wave Oscillator With Capacitive Feedback
Frequency-Enhancement *M. Jahn, H. Knapp, and A. Stelzer* 2009
- Frequency-Hopped Quadrature Frequency Synthesizer in 0.13- μ m Technology
..... *N. R. Lanka, S. A. Patnaik, and R. A. Harjani* 2021
- Frequency Tuning of Wide Temperature Range CMOS LC VCOs *P. C. Maulik and P. W. Lai* 2033
- Crosstalk-Aware PWM-Based On-Chip Links With Self-Calibration in 65 nm CMOS
..... *J. Seo, D. Blaauw, and D. Sylvester* 2041
- A Single-Loop SS-LMS Algorithm With Single-Ended Integrating DFE Receiver for Multi-Drop DRAM Interface
..... *H.-J. Chi, J.-S. Lee, S.-H. Jeon, S.-J. Bae, Y.-S. Sohn, J.-Y. Sim, and H.-J. Park* 2053
- A 5-GHz Direct Digital Frequency Synthesizer Using an Analog-Sine-Mapping Technique in 0.35- μ m SiGe BiCMOS ...
..... *C.-Y. Yang, J.-H. Weng, and H.-Y. Chang* 2064
- A 240-frames/s 2.1-Mpixel CMOS Image Sensor With Column-Shared Cyclic ADCs
..... *S. Lim, J. Cheon, Y. Chae, W. Jung, D.-H. Lee, M. Kwon, K. Yoo, S. Ham, and G. Han* 2073
- A 0.8 ps DNL Time-to-Digital Converter With 250 MHz Event Rate in 65 nm CMOS for Time-Mode-Based $\Sigma\Delta$
Modulator *M. M. Elsayed, V. Dhanasekaran, M. Gambhir, J. Silva-Martinez, and E. Sánchez-Sinencio* 2084
- A Single-Temperature Trimming Technique for MOS-Input Operational Amplifiers Achieving 0.33 μ V/ $^{\circ}$ C Offset Drift ...
..... *M. Bolatkale, M. A. P. Pertijs, W. J. Kindt, J. H. Huijsing, and K. A. A. Makinwa* 2099



A 90–240 MHz Hysteretic Controlled DC-DC Buck Converter With Digital Phase Locked Loop Synchronization	<i>P. Li, D. Bhatia, L. Xue, and R. Bashirullah</i>	2108
Design Techniques for Fully Integrated Switched-Capacitor DC-DC Converters	<i>H.-P. Le, S. R. Sanders, and E. Alon</i>	2120
A Programmable Vision Chip Based on Multiple Levels of Parallel Processors ...	<i>W.-C. Zhang, Q.-Y. Fu, and N.-J. Wu</i>	2132
Generation of Accurate Reference Current for Data Sensing in High-Density Memories by Averaging Multiple Pairs of Dummy Cells	<i>T. Ohsawa, K. Hatsuda, K. Fujita, F. Matsuoka, and T. Higashi</i>	2148
Array Architecture for a Nonvolatile 3-Dimensional Cross-Point Resistance-Change Memory	<i>E. Ou and S. S. Wong</i>	2158
A Scalable Shield-Bitline-Overdrive Technique for Sub-1.5 V Chain FeRAMs	<i>D. Takashima, H. Shiga, D. Hashimoto, T. Miyakawa, S. Shiratake, K. Hoya, R. Ogiwara, R. Takizawa, S. Doumae, R. Fukuda, Y. Watanabe, S. Fujii, T. Ozaki, H. Kanaya, S. Shuto, K. Yamakawa, I. Kunishima, T. Hamamoto, and A. Nitayama</i>	2171
Improvement of Read Margin and Its Distribution by V_{TH} Mismatch Self-Repair in 6T-SRAM With Asymmetric Pass Gate Transistor Formed by Post-Process Local Electron Injection	<i>K. Miyaji, S. Tanakamaru, K. Honda, S. Miyano, and K. Takeuchi</i>	2180

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